

BAT54CV

Two Schottky barrier double diodes in ultra small SOT666 package

Rev. 01 — 22 September 2004

Objective data sheet



1. Product profile

1.1 General description

Two planar Schottky barrier double diodes with common cathodes and an integrated guard ring for stress protection encapsulated in a SOT666 ultra small SMD plastic package.

1.2 Features

- Low forward voltage
- Low capacitance
- Ultra small SMD plastic package
- Flat leads: excellent coplanarity and improved thermal behavior.

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Line termination
- Inverse-polarity protection.

1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_R	continuous reverse voltage		-	-	30	V
I _F	continuous forward current		-	-	200	mA





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2. Pinning information

Table 2: Pinning

	3		
Pin	Description	Simplified outline	Symbol
1	anode (diode 1)		
2	anode (diode 2)	6 5 4	6 5 4
3	common cathode (diode 3, 4)		
4	anode (diode 3)		
5	anode (diode 4)	0	
6	common cathode (diode 1, 2)	13 SOT666	1 2 3 sym057

3. Ordering information

Table 3: Ordering information

Type number	Package		
	Name	Description	Version
BAT54CV	-	plastic surface mounted package; 6 leads	SOT666

4. Marking

Table 4: Marking codes

Type number	Marking code
BAT54CV	C5

5. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	continuous reverse voltage		-	30	V
I _F	continuous forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 10 \text{ ms;} \\ \delta \leq 0.5 \end{array}$	-	0.85	Α
I _{FSM}	non-repetitive peak forward current	$t_p = 8.3 \text{ ms}$	-	2	A
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		-65	+125	°C
T _{stg}	storage temperature		-65	+150	°C

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 Table 5:
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	440	mW

^[1] Refer to SOT666 standard mounting conditions.

6. Thermal characteristics

Table 6: Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	225	K/W

^[1] Refer to SOT666 standard mounting conditions.

7. Characteristics

Table 7: Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	•					
V _F	forward voltage	see Figure 1;	[1]			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		I _F = 1 mA	-	-	320	mV
		I _F = 10 mA	-	-	400	mV
		$I_F = 30 \text{ mA}$	-	-	500	mV
		I _F = 100 mA	-	-	800	mV
I _R	reverse current	V _R = 25 V; see Figure 2	-	-	2	μΑ
C _d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$; see Figure 3	-	-	10	pF

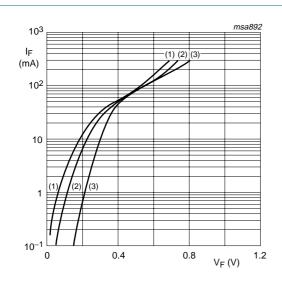
^[1] Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

^[2] Reflow soldering is the only recommended soldering method.

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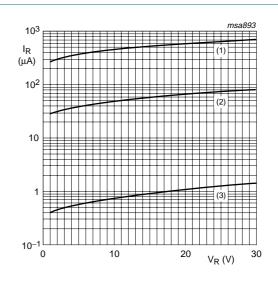
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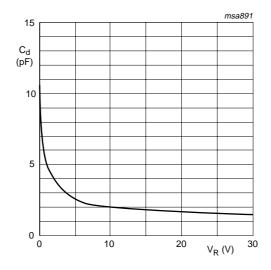
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig 1. Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig 2. Reverse current as a function of reverse voltage; typical values.



 T_{amb} = 25 °C; f = 1 MHz.

Fig 3. Diode capacitance as a function of reverse voltage; typical values.

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8. Package outline

Plastic surface mounted package; 6 leads

SOT666

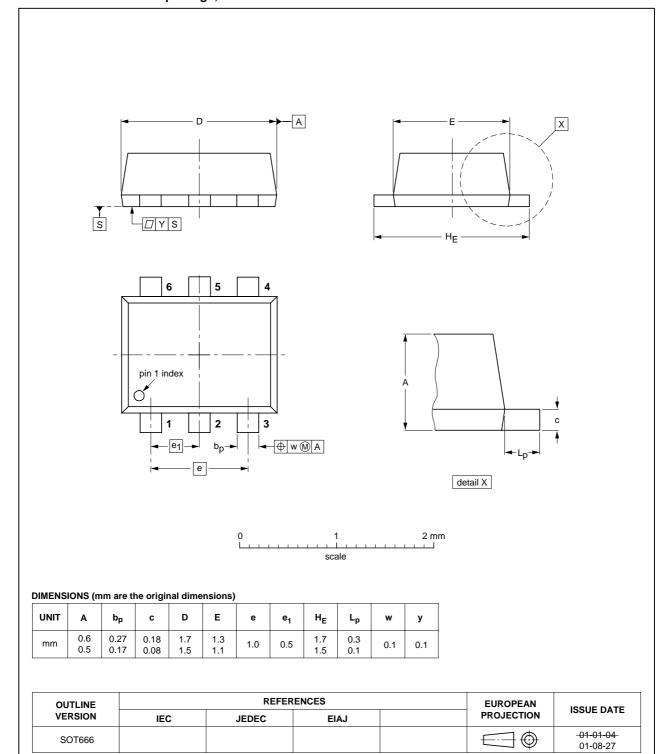


Fig 4. Package outline SOT666.



9. Packing information

Table 8: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity 4000
BAT54CV	SOT666	4 mm pitch, 8 mm tape and reel	-115

^[1] For further information and the availability of packing methods, see <u>Section 14</u>.





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10. Revision history

Table 9: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BAT54CV_1	20040922	Objective data sheet	-	9397 750 13837	-

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11. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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